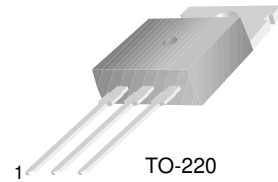


## TIP115/116/117

### Monolithic Construction With Built In Base-Emitter Shunt Resistors

- High DC Current Gain :  $h_{FE}=1000$  @  $V_{CE}=-4V$ ,  $I_C=-1A$  (Min.)
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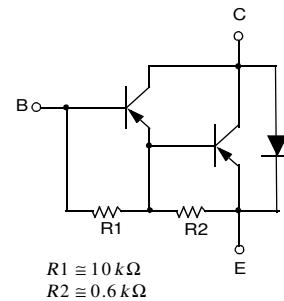
1.Base 2.Collector 3.Emmitter

### PNP Epitaxial Silicon Darlington Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	: TIP115	- 60 V
		: TIP116	- 80 V
		: TIP117	- 100 V
$V_{CEO}$	Collector-Emitter Voltage	: TIP115	- 60 V
		: TIP116	- 80 V
		: TIP117	- 100 V
$V_{EBO}$	Emitter-Base Voltage	- 5	V
$I_C$	Collector Current (DC)	- 2	A
$I_{CP}$	Collector Current (Pulse)	- 4	A
$I_B$	Base Current (DC)	- 50	mA
$P_C$	Collector Dissipation ( $T_a=25^\circ\text{C}$ )	2	W
	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	50	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Equivalent Circuit



#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = -30\text{mA}$ , $I_B = 0$	: TIP115	-60	V
			: TIP116	-80	V
			: TIP117	-100	V
$I_{CEO}$	Collector Cut-off Current	$V_{CE} = -30\text{V}$ , $I_B = 0$ $V_{CE} = -40\text{V}$ , $I_B = 0$ $V_{CE} = -50\text{V}$ , $I_B = 0$		-2	mA
				-2	mA
				-2	mA
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = -60\text{V}$ , $I_E = 0$ $V_{CB} = -80\text{V}$ , $I_E = 0$ $V_{CB} = -100\text{V}$ , $I_E = 0$		-1	mA
				-1	mA
				-1	mA
$I_{EBO}$	Emitter Cut-off Current	$V_{BE} = -5\text{V}$ , $I_C = 0$		-2	mA
$h_{FE}$	DC Current Gain	$V_{CE} = -4\text{V}$ , $I_C = -1\text{A}$ $V_{CE} = -4\text{V}$ , $I_C = -2\text{A}$	1000		
			500		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -2\text{A}$ , $I_B = -8\text{mA}$		-2.5	V
$V_{BE(on)}$	Base-Emitter ON Voltage	$V_{CE} = -4\text{V}$ , $I_C = -2\text{A}$		-2.8	V
$C_{ob}$	Output Capacitance	$V_{CB} = -10\text{V}$ , $I_E = 0$ , $f = 0.1\text{MHz}$		200	pF

# Typical Characteristics

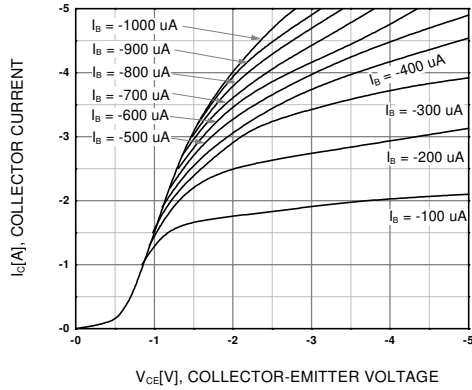


Figure 1. Static Characteristic

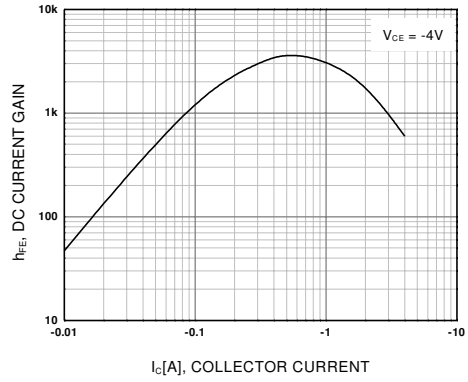


Figure 2. DC current Gain

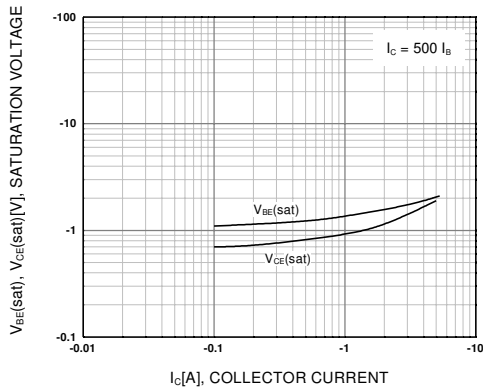


Figure 3. Collector-Emitter Saturation Voltage  
Base-Emitter Saturation Voltage

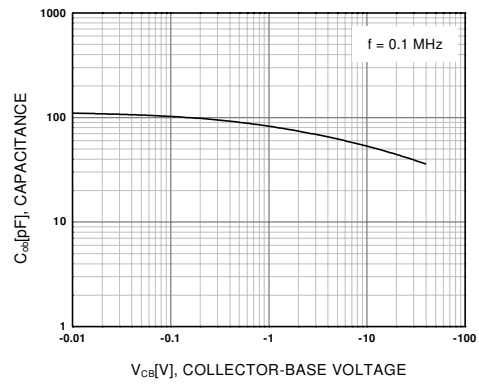


Figure 4. Collector Output Capacitance

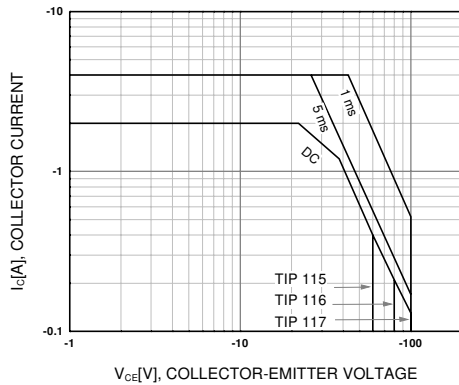


Figure 5. Safe Operating Area

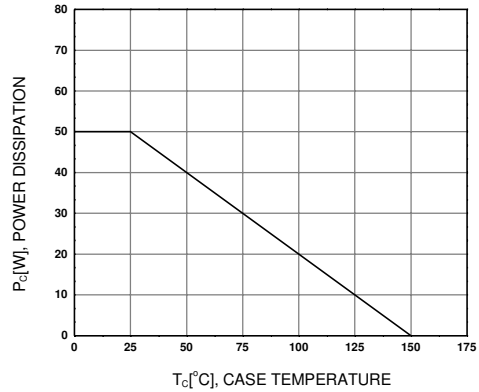
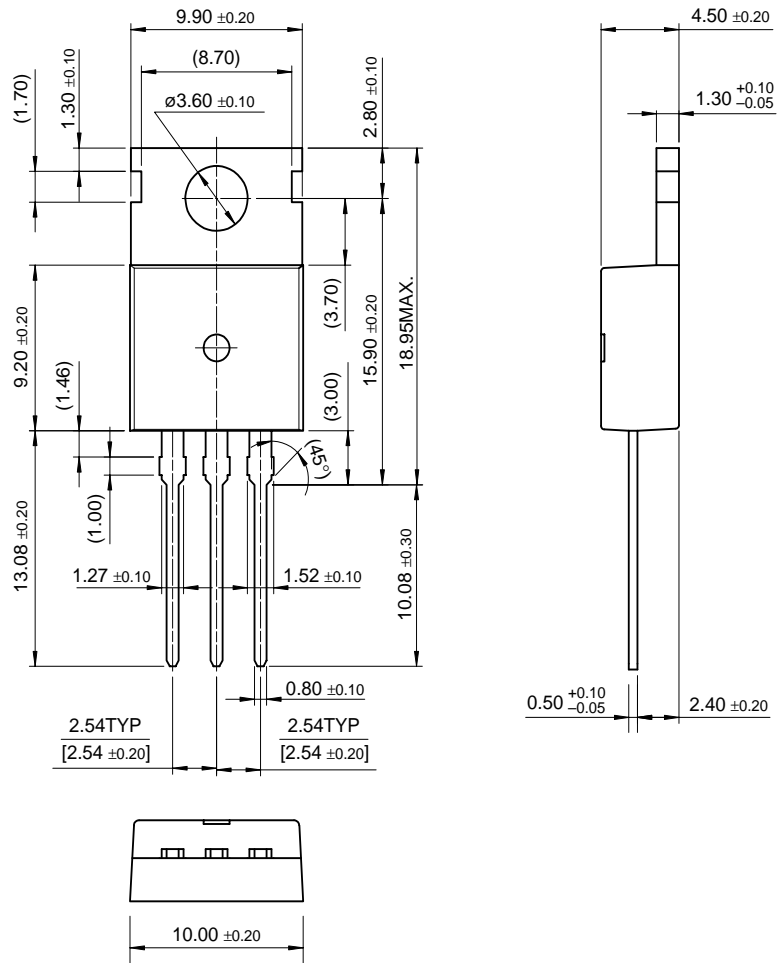


Figure 6. Power Derating

# Package Dimensions

## TO-220

TIP115/116/117



Dimensions in Millimeters

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TIP116  
PNP Epitaxial Silicon Darlington Transistor

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Product	Product status	Pricing*	Package type	Leads	Packing method
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TIP116	Full Production	\$0.362	TO-220	3	BULK

\* 1,000 piece Budgetary Pricing

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